

### Half-Bridge

#### SKiiP 26GB07E3V1

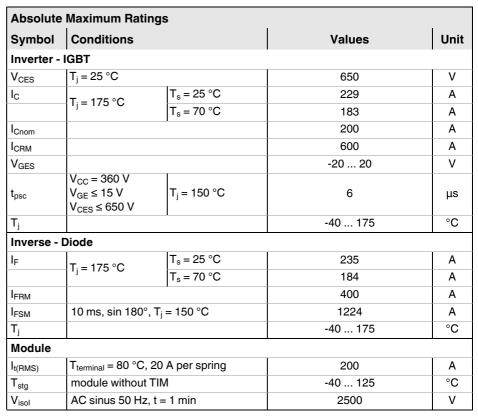
#### Features\*

- 650V Trench IGBTs
- Robust and soft diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532
- NTC T-Sensor

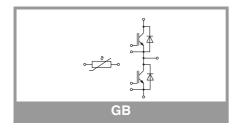
#### **Remarks**

- Max. case temperature limited to T<sub>C</sub>=125°C
- Product reliability results valid for T<sub>j</sub>≤150°C (recommended T<sub>j,op</sub>=-40...+150°C)
- T<sub>j.op</sub>=-40...+150°C)

   MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information



Characte	eristics					
Symbol	Conditions	min.	typ.	max.	Unit	
Inverter -	IGBT		•			•
$V_{GE} = 1$	I <sub>C</sub> = 200 A	T <sub>j</sub> = 25 °C		1.45	1.85	V
	V <sub>GE</sub> = 15 V chiplevel	T <sub>j</sub> = 150 °C		1.70	2.10	V
$V_{CE0}$	chiplevel	T <sub>j</sub> = 25 °C		0.90	1.00	V
	Chipievei	T <sub>j</sub> = 150 °C		0.82	0.90	٧
r <sub>CE</sub>	V <sub>GE</sub> = 15 V chiplevel	T <sub>j</sub> = 25 °C		2.8	4.3	mΩ
		T <sub>j</sub> = 150 °C		4.4	6.0	mΩ
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 3.2$	mA	5	5.8 6.5		V
I <sub>CES</sub>	V <sub>GE</sub> = 0 V V <sub>CE</sub> = 650 V	T <sub>j</sub> = 25 °C			2.0	mA
				-		mA
C <sub>ies</sub>	V <sub>CE</sub> = 25 V V <sub>GE</sub> = 0 V	f = 1 MHz		12.32		nF
C <sub>oes</sub>		f = 1 MHz		0.77		nF
C <sub>res</sub>		f = 1 MHz		0.37		nF
Q <sub>G</sub>	- 8 V+ 15 V			1600		nC
R <sub>Gint</sub>	T <sub>j</sub> = 25 °C			1.0		Ω
t <sub>d(on)</sub>	$V_{CC} = 300 \text{ V}$ $I_{C} = 200 \text{ A}$	T <sub>j</sub> = 150 °C		64		ns
t <sub>r</sub>		T <sub>j</sub> = 150 °C		62		ns
E <sub>on</sub>	$R_{G \text{ on}} = 4 \Omega$ $R_{G \text{ off}} = 4 \Omega$	T <sub>j</sub> = 150 °C		4.4		mJ
t <sub>d(off)</sub>	$di/dt_{on} = 4095 A/\mu s$ $di/dt_{off} = 3935 A/\mu s$	T <sub>j</sub> = 150 °C		486		ns
t <sub>f</sub>		T <sub>j</sub> = 150 °C		60		ns
E <sub>off</sub>		T <sub>j</sub> = 150 °C		7.4		mJ
R <sub>th(j-s)</sub>	per IGBT, λ <sub>paste</sub> =0.8	3 W/(K*m)		0.28		K/W





MiniSKiiP® 2 Dual

Half-Bridge

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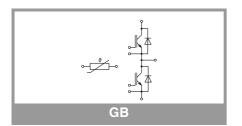
#### Features\*

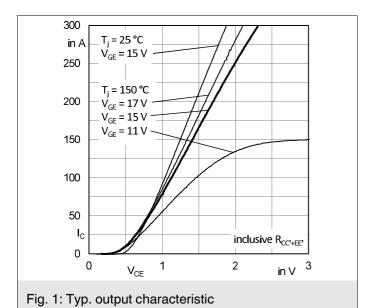
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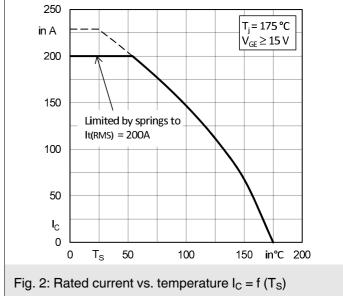
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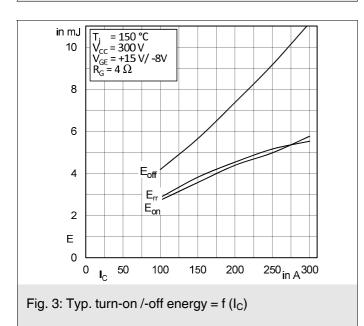
- · Max. case temperature limited to  $T_C=125^{\circ}C$
- Product reliability results valid for  $T_j \le 150$ °C (recommended
- T<sub>j,op</sub>=-40...+150°C)
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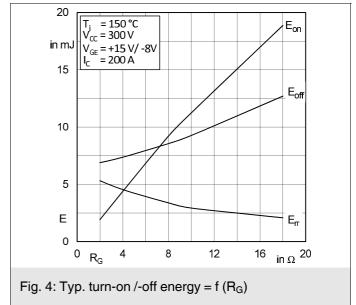
Characteristics							
Symbol	Conditions	min.	typ.	max.	Unit		
Inverse -	Inverse - Diode						
$V_F = V_{EC}$	$I_F = 200 \text{ A}$ $V_{GE} = 0 \text{ V}$ chiplevel	T <sub>j</sub> = 25 °C		1.40	1.76	V	
		T <sub>j</sub> = 150 °C		1.38	1.77	V	
$V_{F0}$	chiplevel	T <sub>j</sub> = 25 °C		1.04	1.24	V	
	Criipievei	T <sub>j</sub> = 150 °C		0.85	0.99	V	
r <sub>F</sub>	J chinlevel	T <sub>j</sub> = 25 °C		1.78	2.6	mΩ	
		T <sub>j</sub> = 150 °C		2.7	3.9	mΩ	
I <sub>RRM</sub>	di/dt <sub>off</sub> = 3754 A/μs V <sub>GE</sub> = -8 V	T <sub>j</sub> = 150 °C		190		Α	
Q <sub>rr</sub>		T <sub>j</sub> = 150 °C		20.6		μC	
E <sub>rr</sub>		T <sub>j</sub> = 150 °C		4.5		mJ	
R <sub>th(j-s)</sub>	per Diode, λ <sub>paste</sub> =0.8 W/(K*m)		0.35			K/W	
Module							
L <sub>CE</sub>				20		nH	
Ms	to heat sink		2		2.5	Nm	
W		50			g		
Temperat	ure Sensor			•		•	
R <sub>100</sub>	T <sub>c</sub> =100°C (R <sub>25</sub> =5 kΩ)			Ω			
B <sub>25/85</sub>	$R_{(T)}=R_{25}*exp[B_{25/85}*(1/T-1/298)], T[K]$		3420			K	

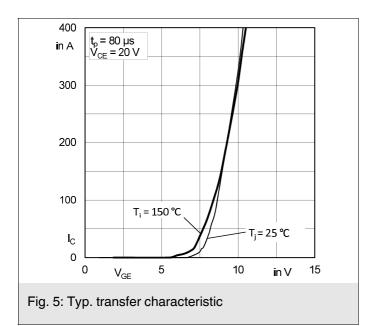


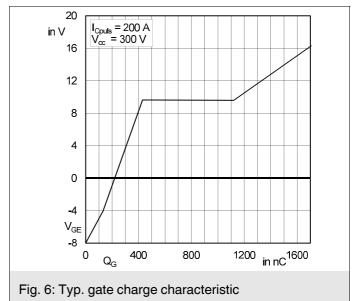


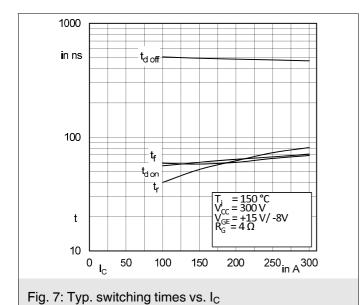


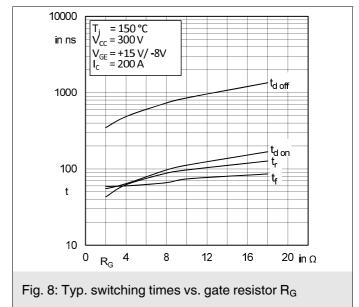


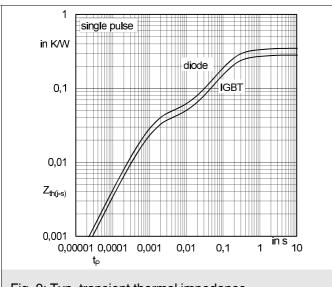


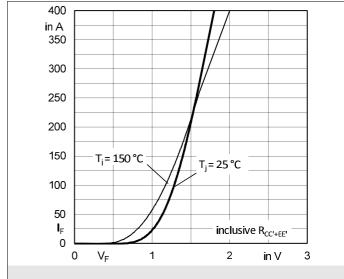












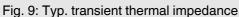
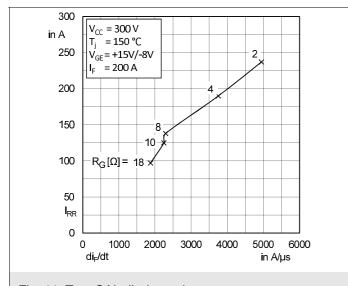


Fig. 10: Typ. CAL diode forward characteristic



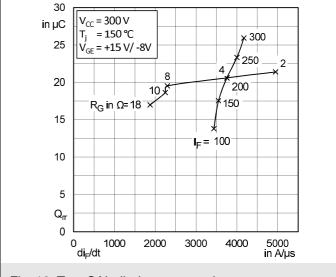
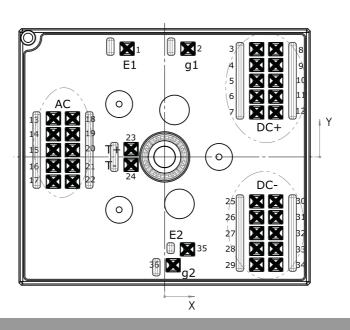


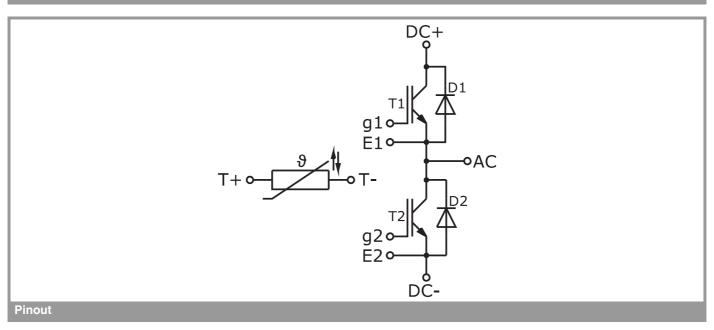
Fig. 11: Typ. CAL diode peak reverse recovery current

Pin out							
Pin	Χ	Y	Function	Pin	X	Υ	Function
1	-7,58	21,9	E1	19	-18,63	4,6	AC
2	4,73	21,9	g1	20	-18,63	1,4	AC
3	18,63	21,8	DC+	21	-18,63	-1,8	AC
4	18,63	18,6	DC+	22	-18,63	-5	AC
5	18,63	15,4	DC+	23	-6,78	1,6	T+
6	18,63	12,2	DC+	24	-6,78	-1,6	T-
7	18,63	9	DC+	25	18,63	-9	DC-
8	22,48	21,8	DC+	26	18,63	-12,2	DC-
9	22,48	18,6	DC+	27	18,63	-15,4	DC-
10	22,48	15,4	DC+	28	18,63	-18,6	DC-
11	22,48	12,2	DC+	29	18,63	-21,8	DC-
12	22,48	9	DC+	30	22,48	-9	DC-
13	-22,48	7,8	AC	31	22,48	-12,2	DC-
14	-22,48	4,6	AC	32	22,48	-15,4	DC-
15	-22,48	1,4	AC	33	22,48	-18,6	DC-
16	-22,48	-1,8	AC	34	22,48	-21,8	DC-
17	-22,48	-5	AC	35	4,63	-18,7	E2
18	-18,63	7,8	AC	36	1,73	-21,9	g2

all values in [mm]



### **Pinout and Dimensions**



This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

#### \*IMPORTANT INFORMATION AND WARNINGS

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